

Ref #	Hits	Search Query	DBs	Default Operator	Plurals	Time Stamp
L1	202199	implant\$3	US-PGPUB; USPAT; USOCR; EPO; JPO; IBM_TDB	OR	ON	2005/09/14 16:52
L2	1016889	hydrogen or h2 or "h.sub.2"	US-PGPUB; USPAT; USOCR; EPO; JPO; IBM_TDB	OR	ON	2005/09/14 16:52
L3	2027257	helium or he or xe or xenon or neon or ne	US-PGPUB; USPAT; USOCR; EPO; JPO; IBM_TDB	OR	ON	2005/09/14 16:53
L5	2798902	2 or 3	US-PGPUB; USPAT; USOCR; EPO; JPO; IBM_TDB	OR	ON	2005/09/14 16:54
L6	9555	1 same 5	US-PGPUB; USPAT; USOCR; EPO; JPO; IBM_TDB	OR	ON	2005/09/14 16:54
L7	427009	(semiconduct\$3 or silicon or gaas or (gallium adj2 (arsenide or nitride)) or inp or (indium adj phosphide)) near3 (wafer\$ or substrate\$1)	US-PGPUB; USPAT; USOCR; EPO; JPO; IBM_TDB	OR	ON	2005/09/14 17:17
L8	47996	(thin or thinning) with 7	US-PGPUB; USPAT; USOCR; EPO; JPO; IBM_TDB	OR	ON	2005/09/14 17:00
L9	399	6 same "back"	US-PGPUB; USPAT; USOCR; EPO; JPO; IBM_TDB	OR	ON	2005/09/14 17:01
L10	474	6 same (back or backside)	US-PGPUB; USPAT; USOCR; EPO; JPO; IBM_TDB	OR	ON	2005/09/14 17:01
L11	89	10 and 8	US-PGPUB; USPAT; USOCR; EPO; JPO; IBM_TDB	OR	ON	2005/09/14 17:03

L13	385	10 not 11	US-PGPUB; USPAT; USOCR; EPO; JPO; IBM_TDB	OR	ON	2005/09/14 17:17
L14	1445096	(semiconduct\$3 or silicon or gaas or (gallium adj2 (arsenide or nitride)) or inp or (indium adj phosphide))	US-PGPUB; USPAT; USOCR; EPO; JPO; IBM_TDB	OR	ON	2005/09/14 17:17
L15	222	13 and 14	US-PGPUB; USPAT; USOCR; EPO; JPO; IBM_TDB	OR	ON	2005/09/14 17:18
L17	32204	(weak\$3 or cleav\$3) near10 (zone\$1 or region\$1)	US-PGPUB; USPAT; USOCR; EPO; JPO; IBM_TDB	OR	ON	2005/09/14 17:46
L18	375	6 and 17	US-PGPUB; USPAT; USOCR; EPO; JPO; IBM_TDB	OR	ON	2005/09/14 17:46
L19	311	11 or 15	US-PGPUB; USPAT; USOCR; EPO; JPO; IBM_TDB	OR	ON	2005/09/14 17:46
L20	355	18 not 19	US-PGPUB; USPAT; USOCR; EPO; JPO; IBM_TDB	OR	ON	2005/09/14 17:46